NCE N-Channel Super Trench II Power MOSFET

Description

The NCEP25ND10AG uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

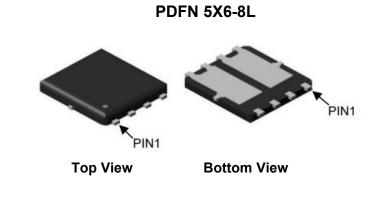
General Features

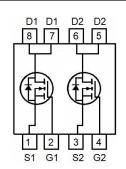
• V_{DS} =100V,I_D =30A

$$\begin{split} R_{DS(ON)} = & 21m\Omega \text{ (typical) } @ \text{ V}_{GS} = & 10\text{V} \\ R_{DS(ON)} = & 27m\Omega \text{ (typical) } @ \text{ V}_{GS} = & 4.5\text{V} \end{split}$$

- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 150 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!





Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P25ND10AG	NCEP25ND10AG	PDFN5X6-8L	Ø330mm	12mm	5000units

Absolute Maximum Ratings (T_c=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	30	Α
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	22	А
Pulsed Drain Current	I _{DM}	120	А
Maximum Power Dissipation	P _D	47	W
Derating factor		0.376	W/℃
Single pulse avalanche energy (Note 1)	E _{AS}	64	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance,Junction-to-Case	Rejc	2.66	°C/W
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NCEP25ND10AG

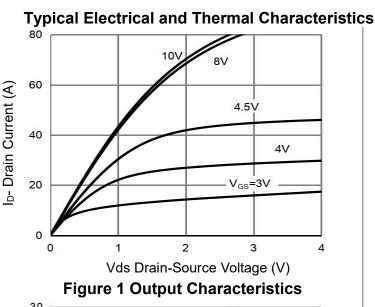
Electrical Characteristics (T_C=25°C unless otherwise noted)

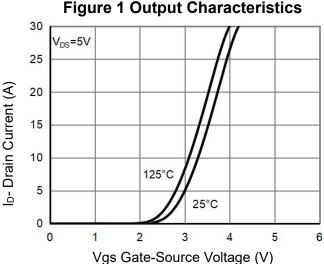
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	100		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20 V , V_{DS} =0 V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.0	1.7	2.5	V
Drain-Source On-State Resistance		V _{GS} =10V, I _D =15A	-	21	25	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =15A	_	27	35	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =15A	-	19	-	S
Dynamic Characteristics						
Input Capacitance	C _{lss}	V 50VV 0V	_	1317.6	-	PF
Output Capacitance	Coss	V_{DS} =50V, V_{GS} =0V, F=1.0MHz	-	123.9	-	PF
Reverse Transfer Capacitance	Crss	Γ-1.0IVIΠZ	-	19.3	-	PF
Switching Characteristics (Note 2)						
Turn-on Delay Time	t _{d(on)}		-	13	-	nS
Turn-on Rise Time	t _r	V_{DD} =50 V , I_D =15 A	-	15	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =3 Ω	-	22	-	nS
Turn-Off Fall Time	t _f		-	6	-	nS
Total Gate Charge	Qg)/ F0)/I 45A	-	27.6	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =50V,I _D =15A,	-	5.5		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	6.9		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =15A	-		1.2	V
Diode Forward Current	Is		-	-	30	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = 15A$	-	40	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs	-	85	-	nC

Notes:

- 1. EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=20V,VG=10V,L=0.5mH,Rg=25 Ω
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=150°C. The SOA curve provides a single pulse rating.

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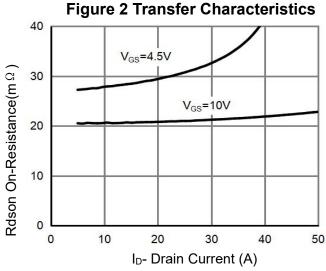


Figure 3 Rdson- Drain Current

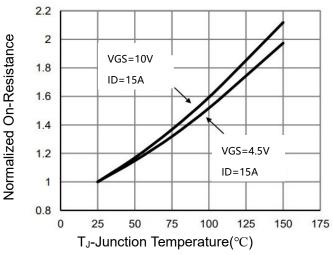
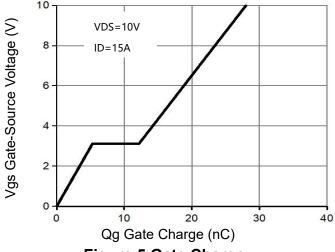


Figure 4 Rdson-Junction Temperature



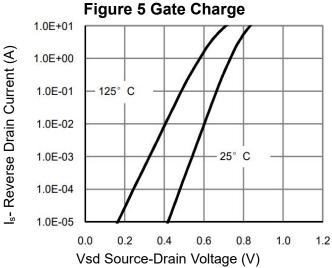
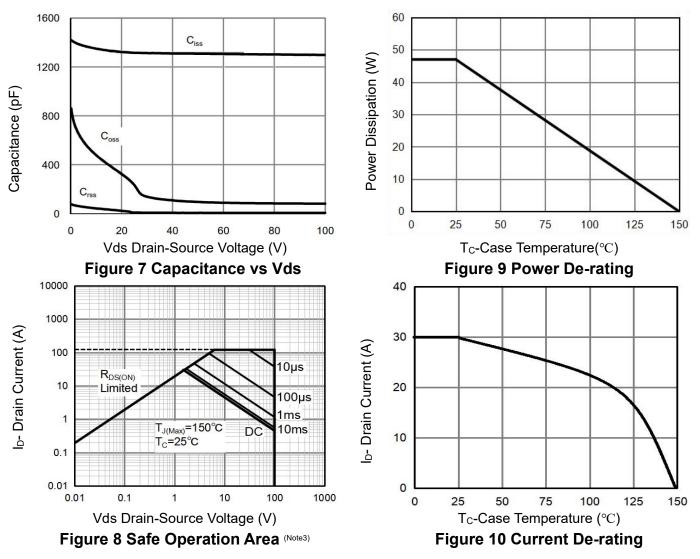


Figure 6 Source- Drain Diode Forward

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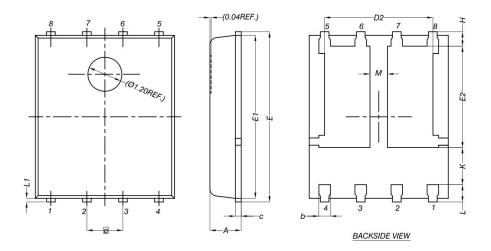


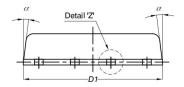
10 Transient Thermal Impedance In descending order r(t), Normalized Effective D=0.5, 0.3, 0.1, 0.05, 0.02, 0.01, single pulse $T_{J.PK} = T_C + P_{DM} \cdot Z_{\theta JC} \cdot R_{\theta JC}$ 0.1 Single Pulse 0.01 1E-05 0.0001 0.001 0.01 0.1 1 10 100

Figure 11 Normalized Maximum Transient Thermal Impedance

Square Wave Pluse Duration(sec)

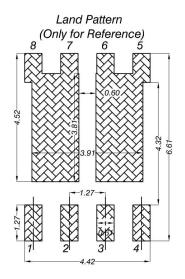
PDFN5X6-8L Package Information







DIM.	MILLIMETERS				
	MIN.	NOM.	MAX.		
Α	0.90	1.00	1.10		
A1	0		0.05		
ь	0.33	0.41	0.51		
С	0.20	0.25	0.30		
D1	4.80	4.90	5.00		
D2	3.61	3.81	3.96		
Ε	5.90	6.00	6.10		
E1	5.70	5.75	5.80		
E2	3.38	3.58	3.78		
е	1.27 BSC				
Н	0.41	0.51	0.61		
K	1.10	-	-		
L L1	0.51	0.61	0.71		
	0.06	0.13	0.20		
М	0.50	-	=		
α	0°	-	12°		



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 1. All Dimension Are In mm.

 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs.
 Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.

 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic
 Body Exclusive Of Mold Flash, Tie Bar, Tie Bar Burrs, Gate Burrs And Interlead Flash,
 But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.

 4. The Package Top May Be Smaller Than The Package Bottom.



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NCEP25ND10AG

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